NSN 5961-01-249-1026

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View Online at https://aerobasegroup.com/nsn/5961-01-249-1026 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **End Application:** An/asb-19 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 259.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter **Current Rating Per Characteristic:** 1.00 nanoamperes zero-gate-voltage source current minor **Power Rating Per Characteristic:** 800.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Color dot indicates supply voltage setting; junction pattern arrangement: npn **Test Data Document:** 82577-3366408 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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